Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.197 inches

Mounting Facility Quantity:

2

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

600.0 repetitive peak off-state voltage and 3.0 gate trigger voltage, instantaneous

Current Rating Per Characteristic:

35.00 amperes forward current, total rms pascal and 300.00 amperes peak forward surge current nanoamperes

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Terminal Type And Quantity:

1 case and 1 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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